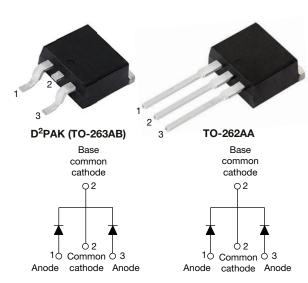
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Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A



VS-MBRB4045CT-M3

VS-MBR4045CT-1-M3

PRIMARY CHARACTE	RISTICS
I _{F(AV)}	2 x 20 A
V _R	45 V
V _F at I _F	0.58 V
I _{RM} max.	95 mA at 125 °C
T _J max.	150 °C
E _{AS}	20 mJ
Package	D ² PAK (TO-263AB), TO-262AA
Circuit configuration	Common cathode

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation



COMPLIANT

HALOGEN

FREE

- Center tap TO-220, D²PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS	AND CHARACTERISTICS		
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform (per device)	40	А
I _{FRM}	T _C = 118 °C (per leg)	40	~
V _{RRM}		45	V
I _{FSM}	t _p = 5 μs sine	900	А
V _F	20 A _{pk} , T _J = 125 °C	0.58	V
TJ	Range	-65 to +150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-MBRB4045CT-M3 VS-MBR4045CT-1-M3	UNITS
Maximum DC reverse voltage	V _R	45	V
Maximum working peak reverse voltage	V _{RWM}	43	v

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ABSOLUTE MAXIMUM RATI	NGS				
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average per leg		T _C = 118 °C, rated V _B		20	
forward current per device	I _{F(AV)}	IC = 110 O, lated VR		40	
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz	z, T _C = 118 °C	40	А
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	900	
peak surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	210	
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 3 \text{ A}, L = 4.4 \text{ m}$	H	20	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	•	3	A

ELECTRICAL SPECIFICATION	ONS				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T ₁ = 25 °C	0.60	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	40 A	- 1j = 25 C	0.78	V
Maximum forward voltage drop	VFM ()	20 A	T ₁ = 125 °C	0.58	-
		40 A	- IJ = 125 C	0.75	
		T _J = 25 °C		1	
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 100 °C	Rated DC voltage	50	mA
		T _J = 125 °C		95	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz), 25 °C	900	pF
Typical series inductance	L _S	Measured from top of term	inal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL	SPECIFIC	ATIONS		
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	e T _J		-65 to 150	°C
Maximum storage temperature range	T _{Stg}		-65 to 175	U
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased (Only for TO-220)	0.50	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (For D ² PAK and TO-262)	50	
Approvimeto weight			2	g
Approximate weight			0.07	oz.
Mounting torque	ı	Non-lubricated threads	6 (5)	kgf · cm
Mounting torque maximun	ı	Non-inducated threads	12 (10)	(lbf · in)
Marking douise		Case style D ² PAK (TO-263AB)	MBRB4	045CT
Marking device		Case style TO-262	MBR40	45CT-1

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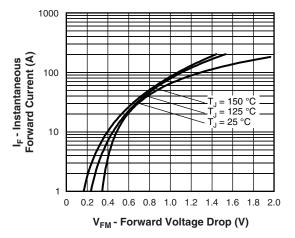
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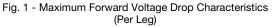
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VS-MBRB4045CT-M3, VS-MBR4045CT-1-M3

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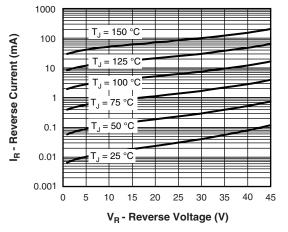


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage (Per Leg)

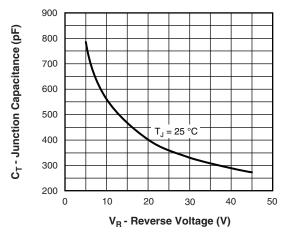


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

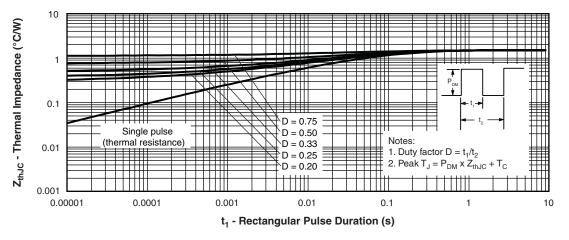


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

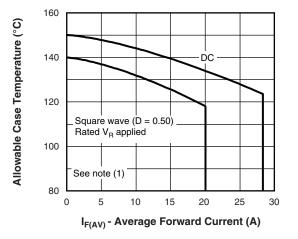
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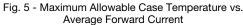
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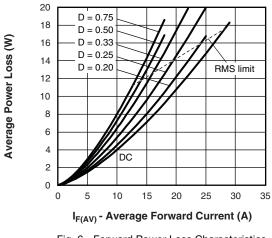


Fig. 6 - Forward Power Loss Characteristics

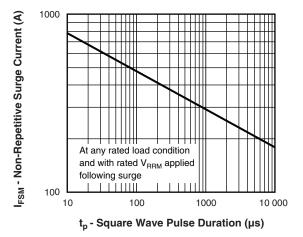
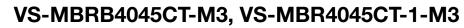


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

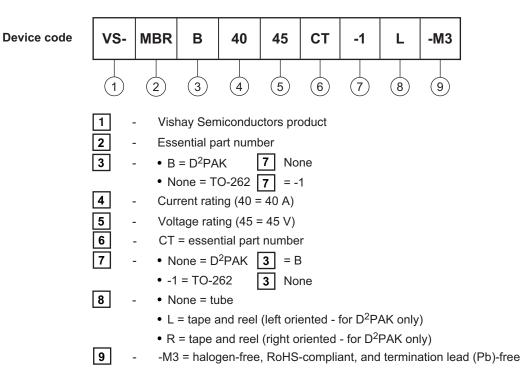
 $^{(1)} \mbox{ Formula used: } T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \mbox{ forward power loss } = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = \ inverse \ power \ loss = V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = \ rated \ V_R$



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ORDERING INFORMATION TABLE

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ORDERING INFORMATI	ON (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-MBRB4045CT-M3	50	1000	Antistatic plastic tube
VS-MBRB4045CTR-M3	800	800	13" diameter reel
VS-MBRB4045CTL-M3	800	800	13" diameter reel
VS-MBR4045CT-1-M3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS					
Dimensions —	D ² PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions	TO-262AA	www.vishay.com/doc?96165			
Part marking information —	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			
SPICE model		www.vishay.com/doc?95296			

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIMETERS		INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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Document Number: 96164

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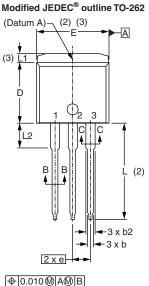
Outline Dimensions

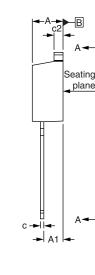


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TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

CVMPOI	MILLIN	MILLIMETERS		HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
 ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis and the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

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